## **Analog Power**

AM3472N

## N-Channel 100V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	$\mathbf{r}_{\mathrm{DS(on)}}\left(\Omega ight)$		I <sub>D</sub> (A)			
100	$0.170 @ V_{GS} = 10$	V	2.9			
100	$0.185 @ V_{GS} = 5.5$	2.7				
TSOP	-6		D,			
Top Vi	ew		Ĺ			
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N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			100	v	
Gate-Source Voltage			±20		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	I <sub>D</sub>	2.9 A		
Pulsed Drain Current <sup>b</sup>			±10	Л	
Continuous Source Current (Diode Conduction) <sup>a</sup>	Is	1.1	А		
Power Dissipation <sup>a</sup> T <sub>A</sub> =25 <sup>o</sup> C		PD	2.0	W	
Operating Junction and Storage Temperature Range		TJ, Tstg	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Тур	Max			
Manimum Innetion to Analizat <sup>a</sup>	t <= 10 sec	R <sub>thJA</sub>	93	110	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	<b>K</b> <sub>thJA</sub>	130	150	C/w	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
Devenue to v	Symphol		Limits			T	
Parame te r	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			v	
Gate-Body Leakage	Igss	$V_{DS} = 0 V$ , $V_{GS} = \pm 8 V$			±100	nA	
Zero Gate Voltage Drain Current	Idas	$V_{DS} = 80 V, V_{GS} = 0 V$		1		uA	
6	IDSS	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uA	
On-State Drain Current <sup>A</sup>	ID(on)	$V_{DS} = 5 V, V_{GS} = 10 V$	10			А	
	<b>5</b> .0( )	$V_{GS} = 10 V$ , $I_D = 1 A$			170	mΩ	
Drain-Source On-Resistance <sup>A</sup>	IDS(on)	$V_{GS} = 5.5 \text{ V}, \text{ ID} = 1 \text{ A}$			185	1162	
Forward Tranconductance <sup>A</sup>	g <sub>fs</sub>	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ A}$		11.3		S	
Diode Forward Voltage	Vsd	Is = 1 A, VGs = 0 V		0.75		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			3			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 10 V$ , $V_{GS} = 5.5 V$ , $I_D = 2.2 A$		1.6		nC	
Gate-Drain Charge	Qgd			1.3			
Turn-On Delay Time	td(on)			8			
Rise Time	tr	$V_{DD} = 10 \overline{V}, \ R_L = 15 \Omega, \ I_D = 1 A,$		4		ne	
Turn-Off Delay Time	td(off)	$V_{GEN} = 4.5 V$		15		ns	
Fall-Time	tf			3			

Notes

- a. Pulse test:  $PW \le 300$  us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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